# **XP04112** (XP4112)

### Silicon PNP epitaxial planar type

For switching/digital circuits

#### Features

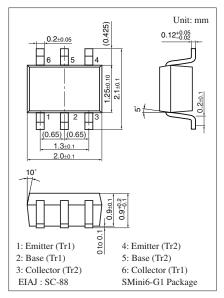
- Two elements incorporated into one package (Transistors with built-in resistor)
- Reduction of the mounting area and assembly cost by one half

#### Basic Part Number

• UNR2112 (UN2112) × 2

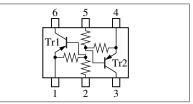
### Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	-50	V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	-50	V
Collector current	I <sub>C</sub>	-100	mA
Total power dissipation	P <sub>T</sub>	150	mW
Junction temperature	Tj	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C



#### Marking Symbol: 6R

#### Internal Connection



#### Symbol Conditions Parameter Min Тур Max Unit Collector-base voltage (Emitter open) V<sub>CBO</sub> $I_{C} = -10 \ \mu A, I_{E} = 0$ -50v $I_{C} = -2 \text{ mA}, I_{B} = 0$ v Collector-emitter voltage (Base open) -50V<sub>CEO</sub> $V_{CB} = -50 \text{ V}, I_E = 0$ Collector-base cutoff current (Emitter open) -0.1μΑ I<sub>CBO</sub> Collector-emitter cutoff current (Base open) $V_{CE} = -50 \text{ V}, I_B = 0$ -0.5μΑ I<sub>CEO</sub> $V_{EB} = -6 V, I_C = 0$ Emitter-base cutoff current (Collector open) -0.2I<sub>EBO</sub> mA $V_{CE} = -10 \text{ V}, I_C = -5 \text{ mA}$ Forward current transfer ratio 60 h<sub>FE</sub> \_\_\_\_ $I_{C} = -10 \text{ mA}, I_{B} = -0.3 \text{ mA}$ Collector-emitter saturation voltage V<sub>CE(sat)</sub> -0.25V $V_{CC} = -5 \text{ V}, V_B = -0.5 \text{ V}, R_L = 1 \text{ k}\Omega$ Output voltage high-level VOH -4.9 V V Output voltage low-level VOL $V_{CC} = -5 \text{ V}, V_B = -2.5 \text{ V}, R_L = 1 \text{ k}\Omega$ -0.2-30% Input resistance $R_1$ 22 +30% kΩ 0.8 1.0 1.2 Resistance ratio $R_1 / R_2$ Transition frequency $V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$ 80 MHz $f_T$

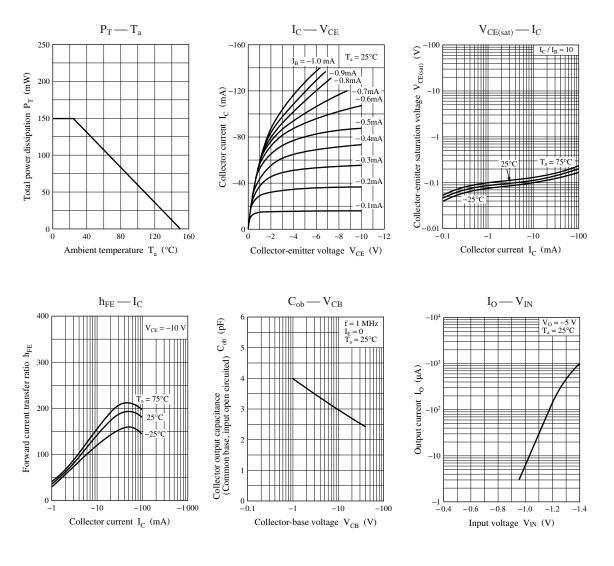
Electrical Characteristics  $T_a = 25^{\circ}C \pm 3^{\circ}C$ 

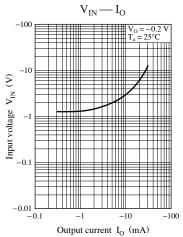
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

Note) The part number in the parenthesis shows conventional part number.

#### XP04112







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